NSN 5962-01-192-7518

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-192-7518 **Body Length:** 1.060 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.130 inches and 0.185 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **Features Provided:** Programmed and high impedance and w/clock and w/enable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Input Circuit Pattern:** 16 input **Terminal Surface Treatment:** Solder **Product Name:** And-or invert gate array **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 12.0 volts power source **Time Rating Per Chacteristic:** 30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Pal **Terminal Type And Quantity:** 20 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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